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UTC SFR1020

DIODE

ULTRA-FAST RECOVERY RECTIFIER DIODES

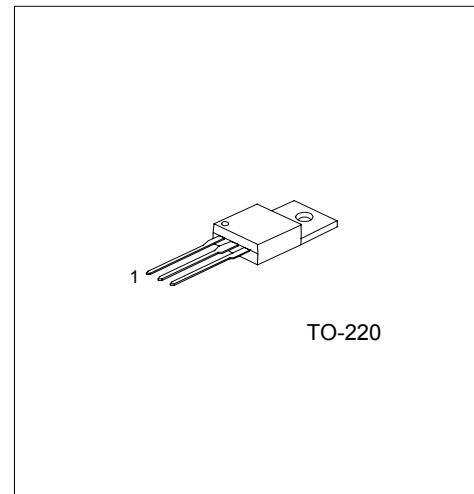
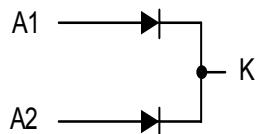
DESCRIPTION

SFR1020 is dual center tap rectifier suited for high frequency Switching Mode Power Supplies applications.

FEATURES

- * HIGH SURGE CURRENT CAPABILITY
- * SUITED FOR SMPS, DC ~ DC CONVERTERS
- * LOW FORWARD AND REVERSE RECOVERY TIME
- * LOW LOSSES

CONNECTION DIAGRAM



1: A1 2: K 3: A2

*Pb-free plating product number: SFR1020L

UTC UNISONIC TECHNOLOGIES CO., LTD.

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1

QW-R601-004,A

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DIODE

ABSOLUTE MAXIMUM RATINGS

(limiting values, per diode)

PARAMETER	SYMBOL	RATINGS	UNIT
Repetitive peak reverse voltage	V_{RRM}	200	V
RMS forward current	$I_{F(RMS)}$	10	A
Average forward current $\bar{I} = 0.5$ $T_c = 125^\circ\text{C}$ (Per diode)	$I_{F(AV)}$	5	A
Surge non repetitive forward current $t_p = 10\text{ms}$ sinusoidal	I_{FSM}	50	A
Storage temperature range	T_{stg}	-60 ~ +150	°C

ELECTRICAL CHARACTERISTICS

(per diode)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Reverse leakage current	I_R *	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			50	µA
		$T_j = 100^\circ\text{C}$				0.6	mA
Forward voltage drop	V_F **	$T_j = 125^\circ\text{C}$	$I_F = 5 \text{ A}$		0.8	0.99	V
		$T_j = 125^\circ\text{C}$	$I_F = 10 \text{ A}$		0.95	1.20	
		$T_j = 25^\circ\text{C}$	$I_F = 10 \text{ A}$			1.25	

* $t_p = 5 \text{ ms}$, $\bar{I} < 2 \%$

** $t_p = 380 \mu\text{s}$, $\bar{I} < 2 \%$

To evaluate the conduction losses use the following equation: $P = 0.78 \times I_{F(AV)} + 0.042 \times I_F^2(\text{RMS})$

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Reverse recovery time	t_{rr}	$T_j = 25^\circ\text{C}$, $I_F = 0.5 \text{ A}$, $I_{rr} = 0.25 \text{ A}$, $I_R = 1 \text{ A}$				30	ns
Forward recovery time	t_{fr}	$T_j = 25^\circ\text{C}$, $I_F = 1 \text{ A}$, $dI_F/dt = 50 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{F \text{ max}}$			20		ns
	V_{FP}	$T_j = 25^\circ\text{C}$, $I_F = 1 \text{ A}$, $dI_F/dt = 50 \text{ A}/\mu\text{s}$			3		V

THERMAL RESISTANCES

PARAMETER	SYMBOL	RATINGS		UNIT
Junction to case	Per diode	$R_{th(j-c)}$	4.0	°C/W
	Total		2.4	
Coupling	$R_{th(c)}$	0.7		

When diodes 1 and 2 are used simultaneously :

$$\Delta T_j (\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

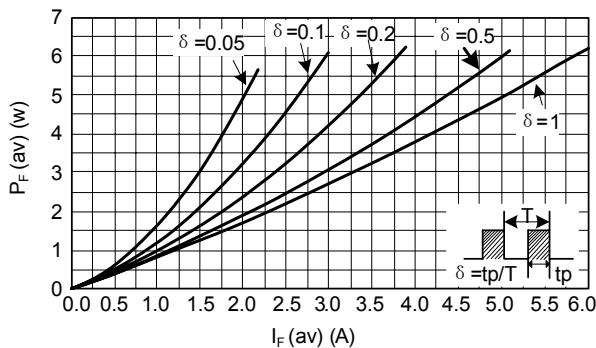
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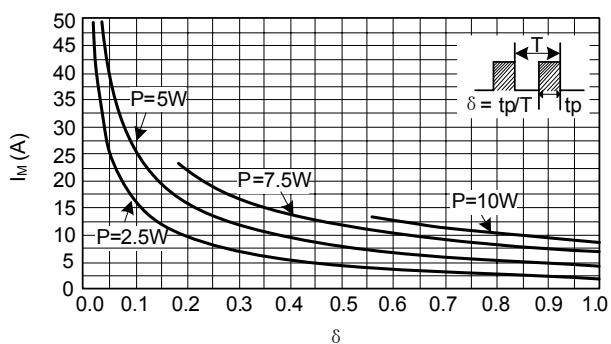
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QW-R601-004,A

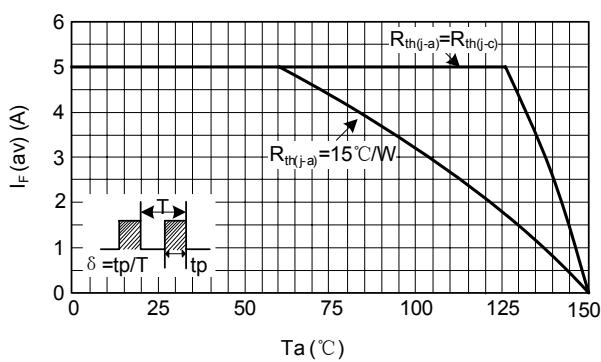
Average forward power dissipation versus average forward current (per diode)



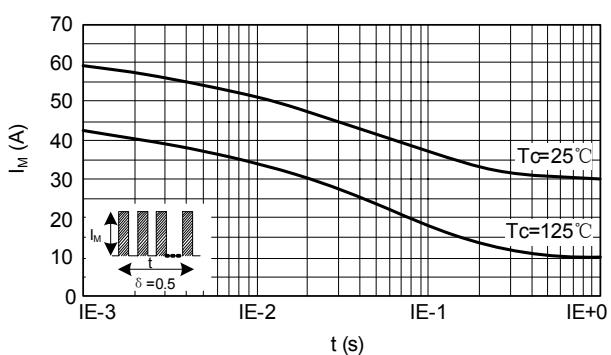
Peak current versus form factor (per diode)



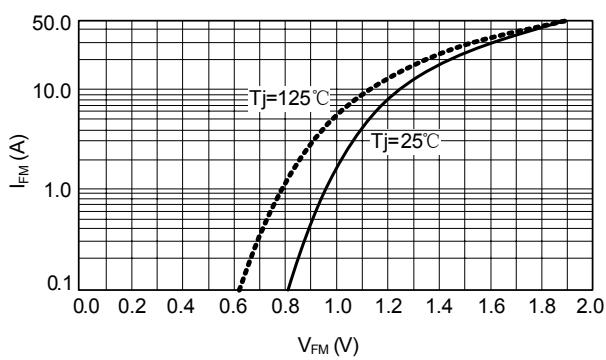
Average forward current versus ambient temperature



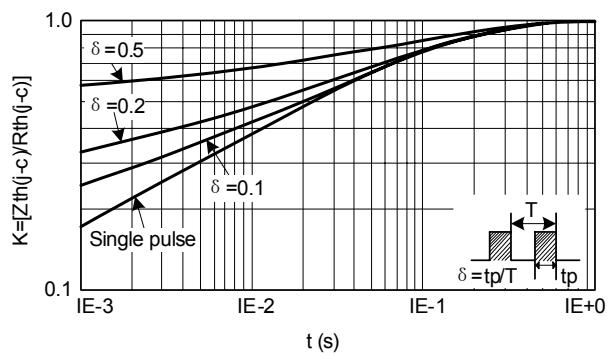
Non repetitive surge peak forward current versus overload duration



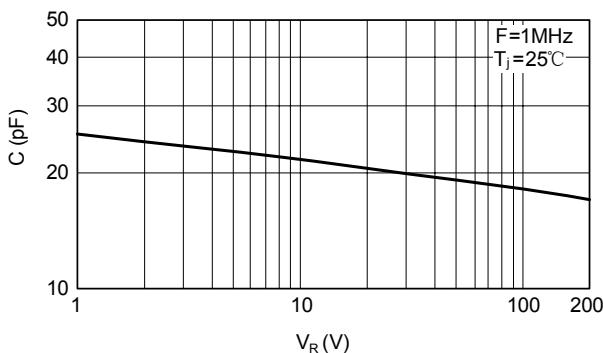
Forward voltage drop versus forward current (maximum values, per diode)



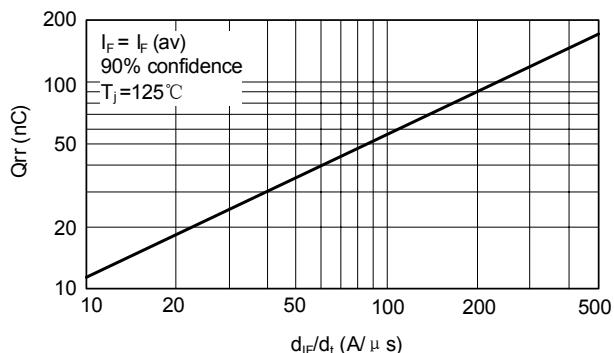
Relative variation of thermal impedance junction to case versus pulse duration



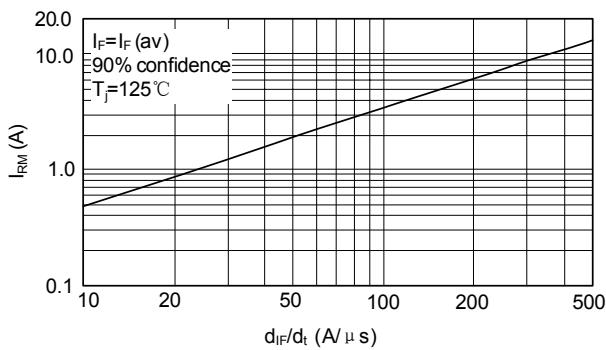
Junction capacitance versus reverse voltage applied (typical values, per diode).



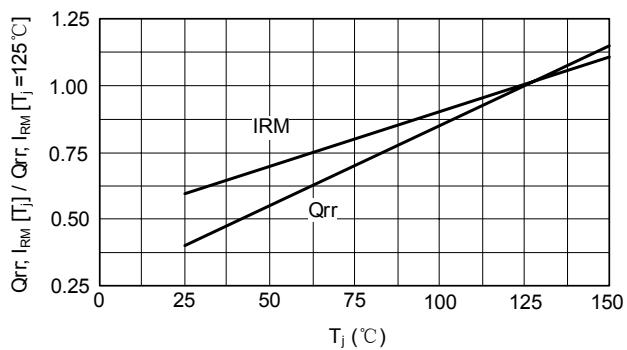
Reverse recovery charges versus d_{IF}/d_t (per diode).



Peak reverse recovery current versus d_{IF}/d_t (per diode).



Dynamic parameters versus junction temperature (per diode)



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